MPSW45A is a Preferred Device

# One Watt Darlington Transistors

# **NPN Silicon**

#### **Features**

• Pb-Free Packages are Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector – Emitter Voltage MPSW45 MPSW45A	V <sub>CES</sub>	40 50	Vdc
Collector – Base Voltage MPSW45 MPSW45A	V <sub>CBO</sub>	50 60	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	12	Vdc
Collector Current – Continuous	I <sub>C</sub>	1.0	Adc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.0 8.0	W mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	2.5 20	W mW/°C
Operating and Store je Junct on Temperature Range	T T tg	-55 to +1: 0	°C

# THERMAL CHARACTERISTICS

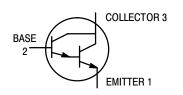
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



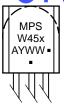
## ON Semiconductor®

http://onsemi.com









MPSW45x = Device Code

x = 45A Devices

A = Assembly Location

Y = Year WW = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 100 μAdc, V <sub>BE</sub> = 0)	MPSW45 MPSW45A	V <sub>(BR)CES</sub>	40 50	- -	Vdc
Collector – Base Breakdown Voltage ( $I_C = 100 \mu Adc, I_E = 0$ )	MPSW45 MPSW45A	V <sub>(BR)CBO</sub>	50 60	- -	Vdc
Emitter – Base Breakdown Voltage ( $I_E = 10 \mu Adc, I_C = 0$ )		V <sub>(BR)EBO</sub>	12	-	Vdc
Collector Cutoff Current $(V_{CB} = 30 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 40 \text{ Vdc}, I_E = 0)$	MPSW45 MPSW45A	I <sub>CBO</sub>	- -	100 100	nAdc
Emitter Cutoff Current (V <sub>EB</sub> = 10 Vdc, I <sub>C</sub> = 0)		I <sub>EBO</sub>	-	100	nAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain ( $I_C = 200 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$ ) ( $I_C = 500 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$ ) ( $I_C = 1.0 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}$ )		h <sub>FE</sub>	25,000 15,000 4,000	150,000 - -	-
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 1.0 Adc, I <sub>B</sub> = 2.0 mAdc)		V <sub>CE(sat)</sub>	-	1.5	Vdc
Base-Emitter Saturation Voltage (I <sub>C</sub> = 1.0 Adc, I <sub>B</sub> = 2.0 mAdc)		V <sub>BE(sat)</sub>	-	2.0	Vdc
Base – Emitter On Voltage (I <sub>C</sub> = 1.0 Adc, V <sub>CE</sub> = 5.0 Vdc)		V <sub>BE(on)</sub>	-	2.0	Vdc
SMALL-SIGNAL CHAPACTERISTICS		$\sim$ m			
Current-Gain - Barkyrig the Fro the (I <sub>C</sub> = 200 mAde, V <sub>CE</sub> = 5.0 Vdc, T = 100 MHz)	U. C		100	-	MHz
Collector–Base Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)		C <sub>cb</sub>	-	6.0	pF

<sup>1.</sup> Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2.0%.

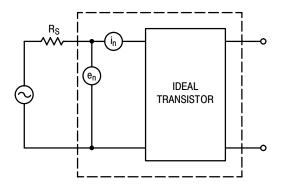


Figure 1. Transistor Noise Model

### **NOISE CHARACTERISTICS**

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$ 

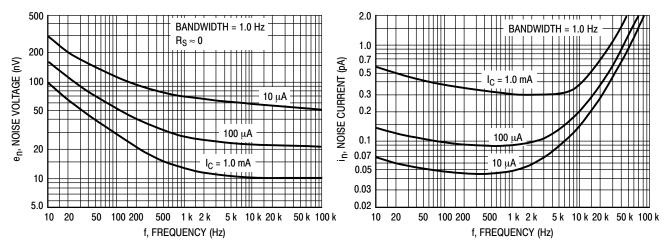


Figure 2. Noise Voltage

Figure 3. Noise Current

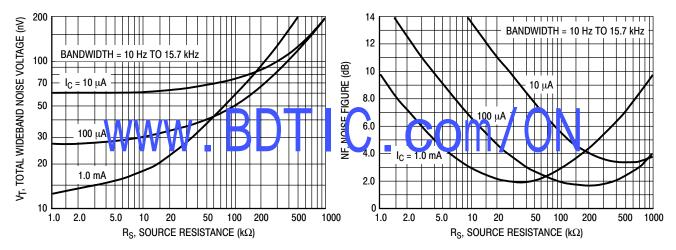


Figure 4. Total Wideband Noise Voltage

Figure 5. Wideband Noise Figure

#### **SMALL-SIGNAL CHARACTERISTICS**

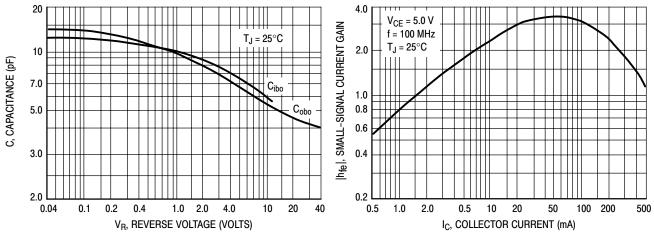


Figure 6. Capacitance

Figure 7. High Frequency Current Gain

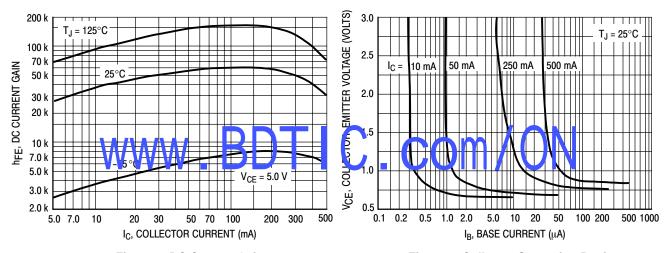


Figure 8. DC Current Gain

Figure 9. Collector Saturation Region

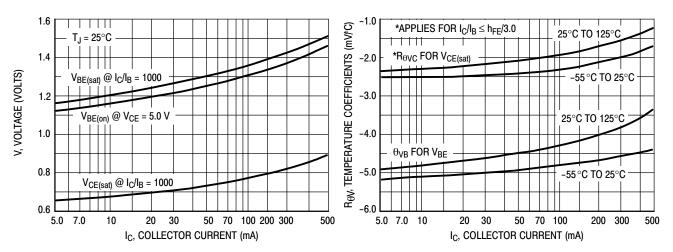


Figure 10. "On" Voltages

Figure 11. Temperature Coefficients

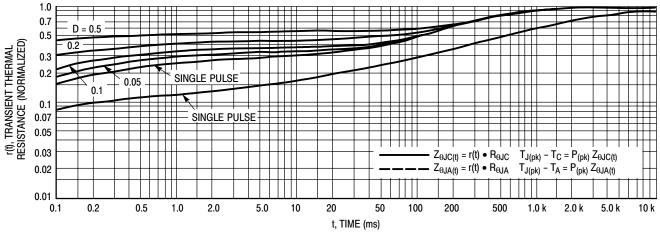


Figure 12. Thermal Response

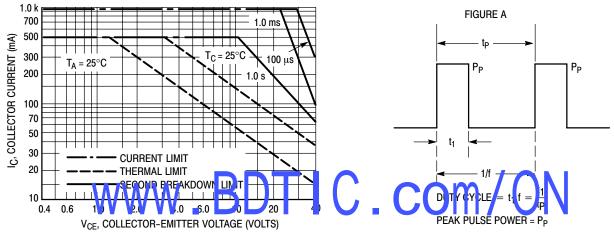


Figure 13. Active Region Safe Operating Area

**Design Note: Use of Transient Thermal Resistance Data** 

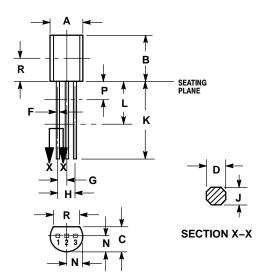
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>	
MPSW45	TO-92	5,000 Units / Box	
MPSW45G	TO-92 (Pb-Free)	5,000 Units / Box	
MPSW45RLRE	TO-92	2,000 / Tape & Reel	
MPSW45RLREG	TO-92 (Pb-Free)	2,000 / Tape & Reel	
MPSW45A	TO-92	5,000 Units / Box	
MPSW45AG	TO-92 (Pb-Free)	5,000 Units / Box	
MPSW45ARLRA	TO-92	2,000 / Tape & Reel	
MPSW45ARLRAG	TO-92 (Pb-Free)	2,000 / Tape & Reel	
MPSW45AZL1	TO-92	2,000 / Ammo Pack	
MPSW45AZL1G	TO-92 (Pb-Free)	2,000 / Ammo Pack	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **PACKAGE DIMENSIONS**

TO-92 (TO-226) CASE 29-10 ISSUE AL



#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
  Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- 4. DIMENSION F APPLIES BETWEEN P AND L DIMENSIONS D AND J APPLY BETWEEN L AND K MIMIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.457	0.533
F	0.016	0.019	0.407	0.482
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.135		3 //3	

STYLE 1: PIN 1.

PIN 1. EMITTER 2. BASE

2. BASE 3. COLLECTOR

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